

# Abstracts

## A 2-V operation RF front-end GaAs MMIC for PHS hand-set (1998 Vol. I [MWSYM])

---

*T. Seshita, K. Kawakyu, W. Wakimoto, M. Nagaoka, Y. Kitaura and N. Uchitomi. "A 2-V operation RF front-end GaAs MMIC for PHS hand-set (1998 Vol. I [MWSYM])." 1998 MTT-S International Microwave Symposium Digest 98.1 (1998 Vol. I [MWSYM]): 167-170.*

A single 2-V operation RF front-end MMIC has been developed using three kinds of self-aligned gate MESFETs. Its transmitter block of a power amplifier with an antenna switch exhibited a power gain of 28.9 dB and a high power-added efficiency of 27.0% at 20.5-dBm output power. The receiver block of a low-noise amplifier with the antenna switch exhibits a noise figure of 3.4 dB and a gain of 11.1 dB.

[Return to main document.](#)